

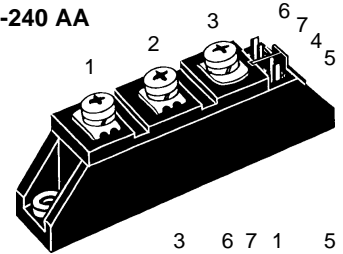
# Thyristor Modules

## Thyristor/Diode Modules

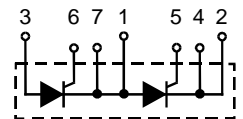
**$I_{TRMS} = 2x 100 A$**   
 **$I_{TAVM} = 2x 64 A$**   
 **$V_{RRM} = 800-1800 V$**

| $V_{RSM}$<br>$V_{DSM}$ | $V_{RRM}$<br>$V_{DRM}$ | Type           |                |
|------------------------|------------------------|----------------|----------------|
| V                      | V                      | Version 1      | Version 8      |
| 900                    | 800                    | MCC 56-08io1 B | MCD 56-08io1 B |
| 1300                   | 1200                   | MCC 56-12io1 B | MCD 56-12io1 B |
| 1500                   | 1400                   | MCC 56-14io1 B | --             |
| 1700                   | 1600                   | MCC 56-16io1 B | MCD 56-16io1 B |
| 1900                   | 1800                   | MCC 56-18io1 B | --             |
| 1500                   | 1400                   | MCC 56-14io8 B | MCD 56-14io8 B |
| 1700                   | 1600                   | MCC 56-16io8 B | MCD 56-16io8 B |
| 700                    | 600                    | MDC 56-06io1 B |                |

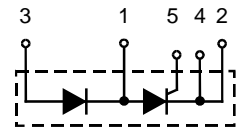
TO-240 AA



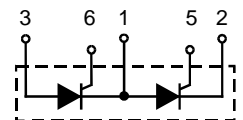
MCC  
Version 1



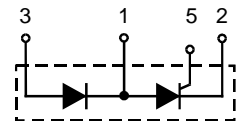
MCD  
Version 1



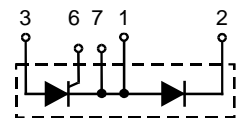
MCC  
Version 8



MCD  
Version 8



MDC  
Version 1



| Symbol                                       | Test Conditions   | Maximum Ratings   |                                |                        |
|--|---|---|--------------------------------|------------------------|
| $I_{TRMS}, I_{FRMS}$<br>$I_{TAVM}, I_{FAVM}$ | $T_{VJ} = T_{VJM}$<br>$T_C = 83^\circ C; 180^\circ \text{ sine}$<br>$T_C = 85^\circ C; 180^\circ \text{ sine}$                  | 100<br>64<br>60   | A<br>A<br>A                    |                        |
| $I_{TSM}, I_{FSM}$                           | $T_{VJ} = 45^\circ C;$<br>$V_R = 0$<br>$t = 10 \text{ ms (50 Hz), sine}$<br>$t = 8.3 \text{ ms (60 Hz), sine}$                  | 1500<br>1600  | A<br>A                         |                        |
| $\int i^2 dt$                                | $T_{VJ} = 45^\circ C$<br>$V_R = 0$<br>$t = 10 \text{ ms (50 Hz), sine}$<br>$t = 8.3 \text{ ms (60 Hz), sine}$                   | 11 200<br>10 750  | $A^2s$<br>$A^2s$               |                        |
| $(di/dt)_{cr}$                               | $T_{VJ} = T_{VJM}$<br>$f = 50 \text{ Hz}, t_p = 200 \mu s$<br>$V_D = 2/3 V_{DRM}$<br>$I_G = 0.45 A$<br>$di_G/dt = 0.45 A/\mu s$ | repetitive, $I_T = 150 A$<br>non repetitive, $I_T = I_{TAVM}$ | 150<br>500                     | $A/\mu s$<br>$A/\mu s$ |
| $(dv/dt)_{cr}$                               | $T_{VJ} = T_{VJM};$<br>$R_{GK} = \infty; \text{ method 1 (linear voltage rise)}$  | $V_{DR} = 2/3 V_{DRM}$  | 1000                           | $V/\mu s$              |
| $P_{GM}$                                     | $T_{VJ} = T_{VJM}$<br>$I_T = I_{TAVM}$  | $t_p = 30 \mu s$<br>$t_p = 300 \mu s$                         | 10<br>5                        | W<br>W                 |
| $P_{GAV}$                                    |   |   | 0.5                            | W                      |
| $V_{RGM}$                                    |   |   | 10                             | V                      |
| $T_{VJ}$                                     |   |   | -40...+125                     | $^\circ C$             |
| $T_{VJM}$                                    |   |   | 125                            | $^\circ C$             |
| $T_{stg}$                                    |   |   | -40...+125                     | $^\circ C$             |
| $V_{ISOL}$                                   | 50/60 Hz, RMS<br>$I_{ISOL} \leq 1 \text{ mA}$   | $t = 1 \text{ min}$<br>$t = 1 \text{ s}$                      | 3000<br>3600                   | $V\sim$<br>$V\sim$     |
| $M_d$  | Mounting torque (M5)<br>Terminal connection torque (M5)   |   | 2.5-4.0/22-35<br>2.5-4.0/22-35 | Nm/lb.in.<br>Nm/lb.in. |
| Weight                                       | Typical including screws  |   | 90                             | g                      |

### Features

- International standard package, JEDEC TO-240 AA
- Direct copper bonded  $Al_2O_3$  -ceramic base plate
- Planar passivated chips
- Isolation voltage 3600 V~
- UL registered, E 72873
- Gate-cathode twin pins for version 1B

### Applications

- DC motor control
- Softstart AC motor controller
- Light, heat and temperature control

### Advantages

- Space and weight savings
- Simple mounting with two screws
- Improved temperature and power cycling
- Reduced protection circuits

Data according to IEC 60747 and refer to a single thyristor/diode unless otherwise stated. IXYS reserves the right to change limits, test conditions and dimensions

| Symbol             | Test Conditions  | Characteristic Values |
|--------------------|--|-----------------------|
| $I_{RRM}, I_{DRM}$ | $T_{VJ} = T_{VJM}; V_R = V_{RRM}; V_D = V_{DRM}$   | 5 mA                  |
| $V_T, V_F$         | $I_T, I_F = 200 \text{ A}; T_{VJ} = 25^\circ\text{C}$  | 1.57 V                |
| $V_{T0}$           | For power-loss calculations only ( $T_{VJ} = 125^\circ\text{C}$ )  | 0.85 V                |
| $r_T$              |  | 3.7 mΩ                |
| $V_{GT}$           | $V_D = 6 \text{ V}; T_{VJ} = 25^\circ\text{C}$   | 1.5 V                 |
|                    | $T_{VJ} = -40^\circ\text{C}$   | 1.6 V                 |
| $I_{GT}$           | $V_D = 6 \text{ V}; T_{VJ} = 25^\circ\text{C}$   | 100 mA                |
|                    | $T_{VJ} = -40^\circ\text{C}$   | 200 mA                |
| $V_{GD}$           | $T_{VJ} = T_{VJM}; V_D = 2/3 V_{DRM}$  | 0.2 V                 |
| $I_{GD}$           |  | 10 mA                 |
| $I_L$              | $T_{VJ} = 25^\circ\text{C}; t_p = 10 \mu\text{s}; V_D = 6 \text{ V}$<br>$I_G = 0.45 \text{ A}; di_G/dt = 0.45 \text{ A}/\mu\text{s}$   | 450 mA                |
| $I_H$              | $T_{VJ} = 25^\circ\text{C}; V_D = 6 \text{ V}; R_{GK} = \infty$  | 200 mA                |
| $t_{gd}$           | $T_{VJ} = 25^\circ\text{C}; V_D = 1/2 V_{DRM}$<br>$I_G = 0.45 \text{ A}; di_G/dt = 0.45 \text{ A}/\mu\text{s}$   | 2 μs                  |
| $t_q$              | $T_{VJ} = T_{VJM}; I_T = 150 \text{ A}, t_p = 200 \mu\text{s}; -di/dt = 10 \text{ A}/\mu\text{s}$ typ.<br>$V_R = 100 \text{ V}; dv/dt = 20 \text{ V}/\mu\text{s}; V_D = 2/3 V_{DRM}$ | 150 μs                |
| $Q_S$              | $T_{VJ} = T_{VJM}; I_T, I_F = 50 \text{ A}, -di/dt = 3 \text{ A}/\mu\text{s}$  | 100 μC                |
| $I_{RM}$           |  | 24 A                  |
| $R_{thJC}$         | per thyristor/diode; DC current per module   | 0.45 K/W              |
| $R_{thJK}$         | per thyristor/diode; DC current per module   | 0.225 K/W             |
|                    | other values see Fig. 8/9  | 0.65 K/W              |
|                    |  | 0.325 K/W             |
| $d_s$              | Creepage distance on surface   | 12.7 mm               |
| $d_A$              | Strike distance through air  | 9.6 mm                |
| $a$                | Maximum allowable acceleration   | 50 m/s <sup>2</sup>   |

Optional accessories for module-type MCC 56 version 1 B

Keyed gate/cathode twin plugs with wire length = 350 mm, gate = yellow, cathode = red

Type ZY 200L (L = Left for pin pair 4/5) } UL 758, style 1385,  
Type ZY 200R (R = right for pin pair 6/7) } CSA class 5851, guide 460-1-1

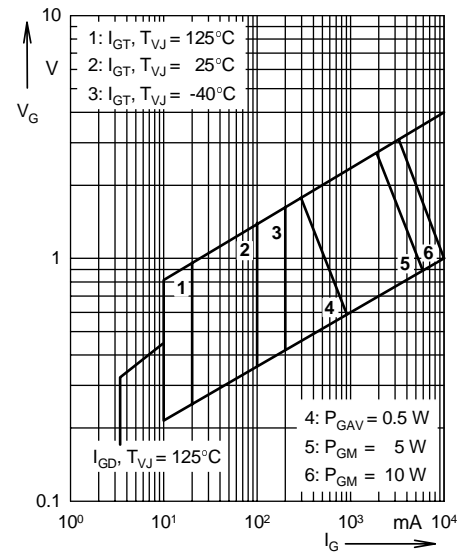


Fig. 1 Gate trigger characteristics

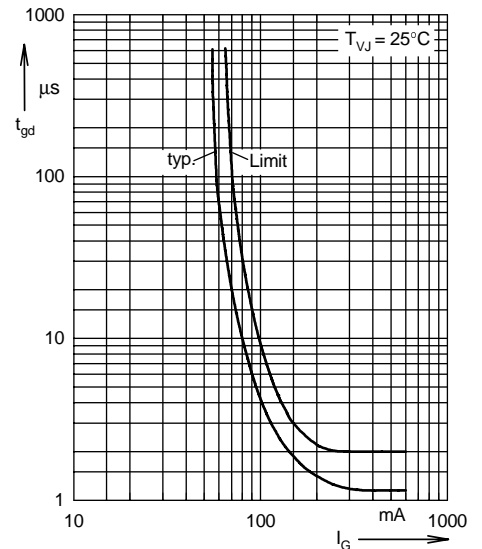
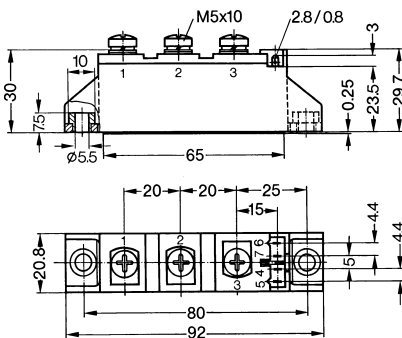


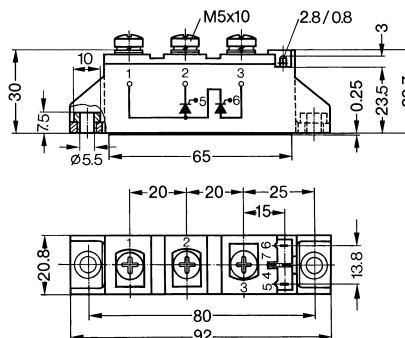
Fig. 2 Gate trigger delay time

Dimensions in mm (1 mm = 0.0394")

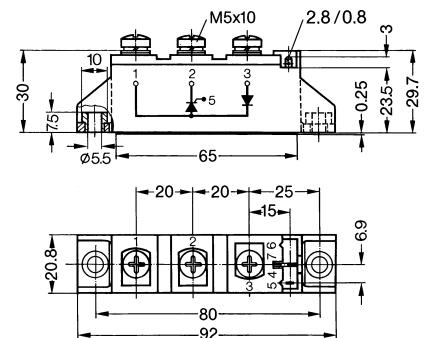
MCC / MCD / MDC Version 1 B



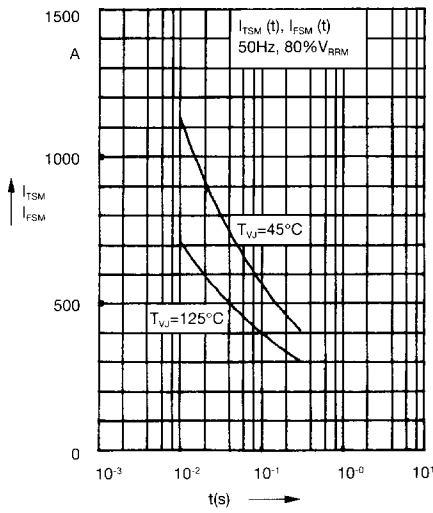
MCC Version 8 B



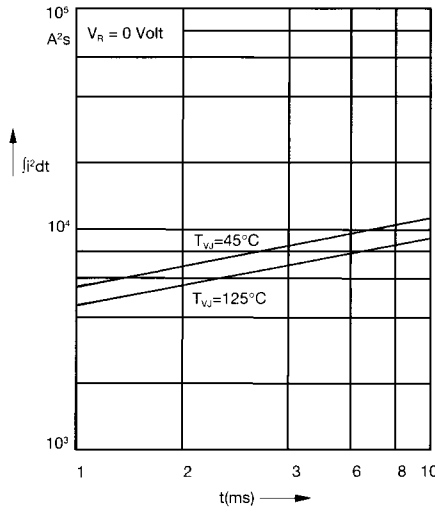
MCD Version 8 B



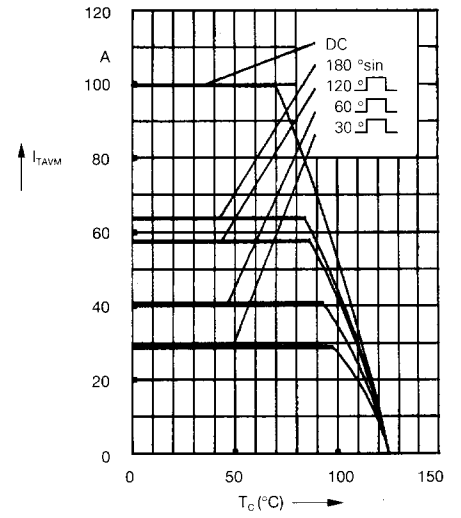
Version 1 or 8 without B in typ designation = without insert in mountig holes



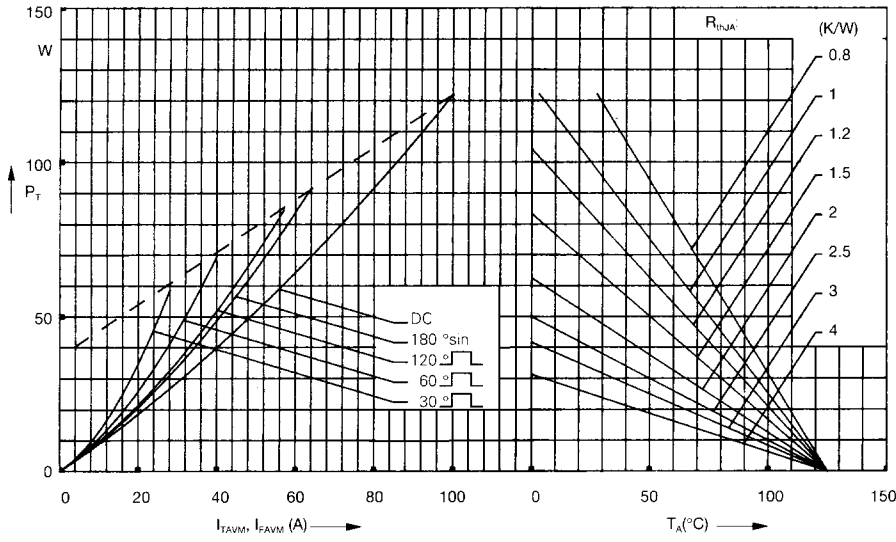
**Fig. 3 Surge overload current**  
 $I_{TSM}, I_{FSM}$ : Crest value,  $t$ : duration



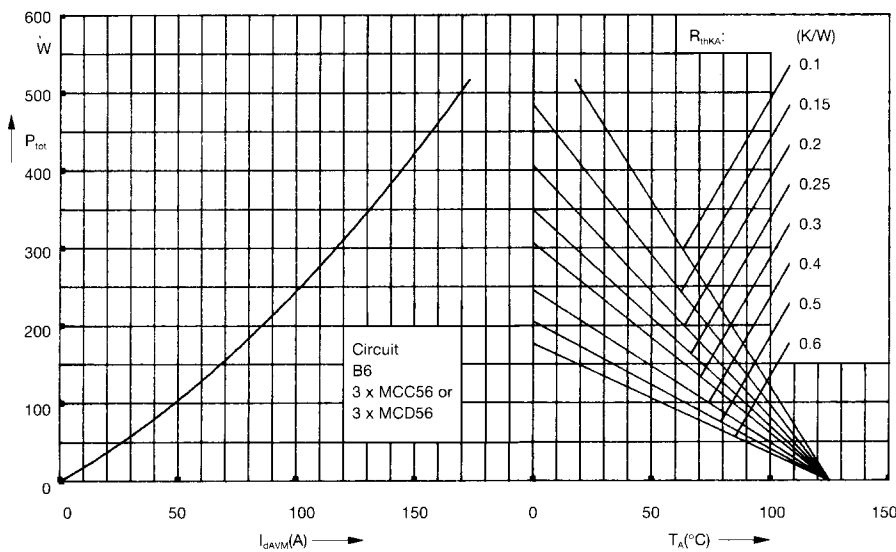
**Fig. 4  $\int i^2 dt$  versus time (1-10 ms)**



**Fig. 4a Maximum forward current at case temperature**



**Fig. 5 Power dissipation versus on-state current and ambient temperature (per thyristor or diode)**



**Fig. 6 Three phase rectifier bridge: Power dissipation versus direct output current and ambient temperature**

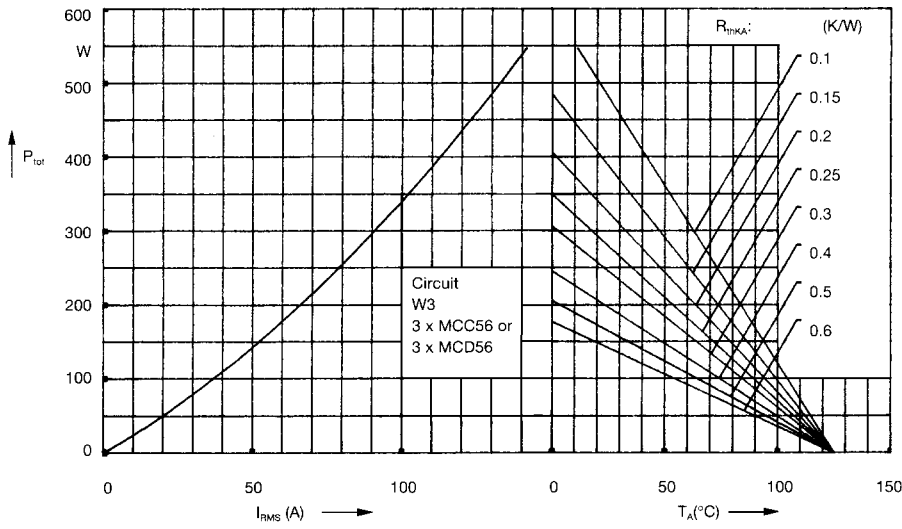


Fig. 7 Three phase AC-controller: Power dissipation versus RMS output current and ambient temperature

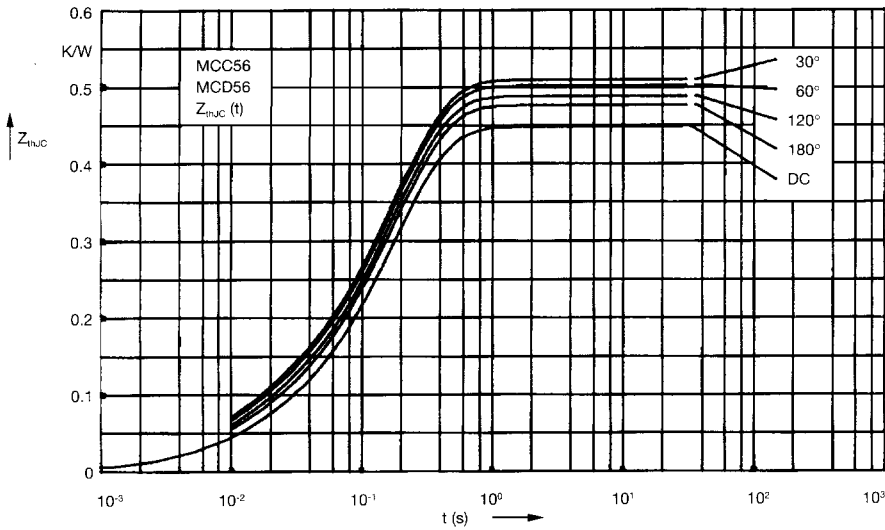


Fig. 8 Transient thermal impedance junction to case (per thyristor or diode)

$R_{thJC}$  for various conduction angles d:

| d    | $R_{thJC}$ (K/W) |
|------|------------------|
| DC   | 0.45             |
| 180° | 0.47             |
| 120° | 0.49             |
| 60°  | 0.505            |
| 30°  | 0.52             |

Constants for  $Z_{thJC}$  calculation:

| i | $R_{thi}$ (K/W) | $t_i$ (s) |
|---|-----------------|-----------|
| 1 | 0.014           | 0.015     |
| 2 | 0.026           | 0.0095    |
| 3 | 0.41            | 0.175     |

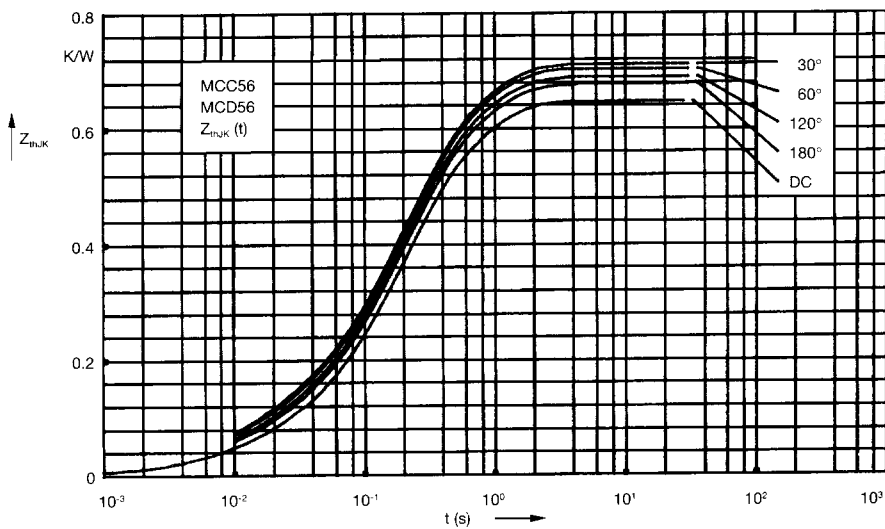


Fig. 9 Transient thermal impedance junction to heatsink (per thyristor or diode)

$R_{thJK}$  for various conduction angles d:

| d    | $R_{thJK}$ (K/W) |
|------|------------------|
| DC   | 0.65             |
| 180° | 0.67             |
| 120° | 0.69             |
| 60°  | 0.705            |
| 30°  | 0.72             |

Constants for  $Z_{thJK}$  calculation:

| i | $R_{thi}$ (K/W) | $t_i$ (s) |
|---|-----------------|-----------|
| 1 | 0.014           | 0.015     |
| 2 | 0.026           | 0.0095    |
| 3 | 0.41            | 0.175     |
| 4 | 0.2             | 0.67      |